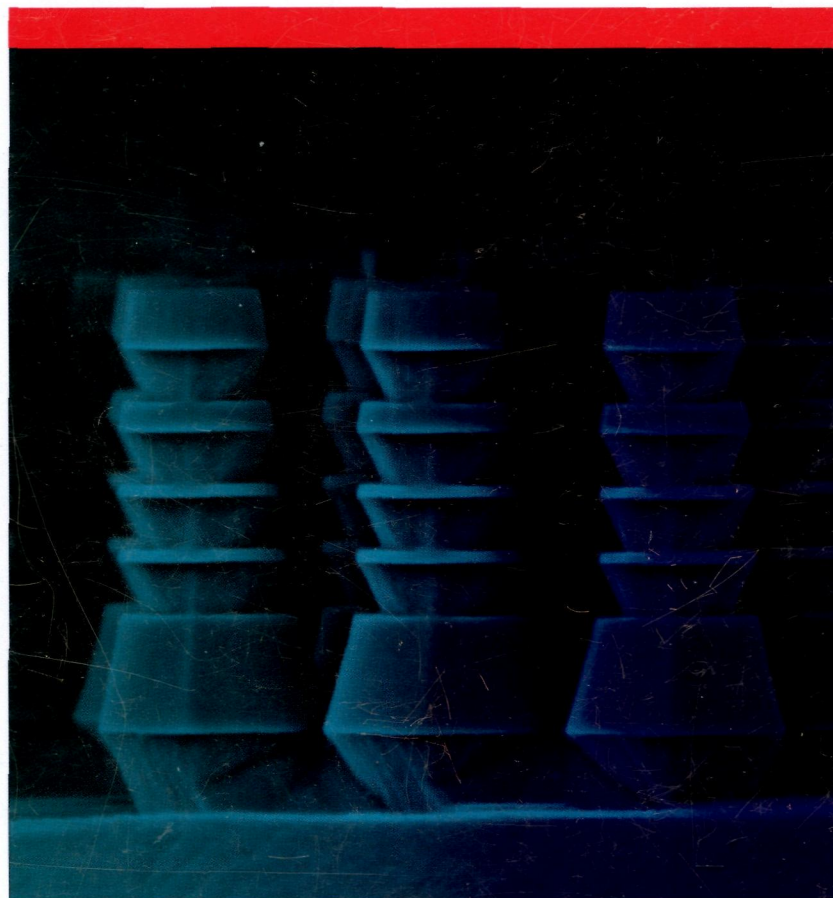


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Featured article

Generation of substrate-free III-V nanodisks
from user-defined multilayer nanopillar
arrays for integration on Si

S Naureen, N Shahid, A Dev and S Anand

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